

### **isc Silicon NPN Power Transistor**

# 3DD13009NL

### **DESCRIPTION**

- · High breakdown voltage
- · High switching speed
- · High current capability
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### **APPLICATIONS**

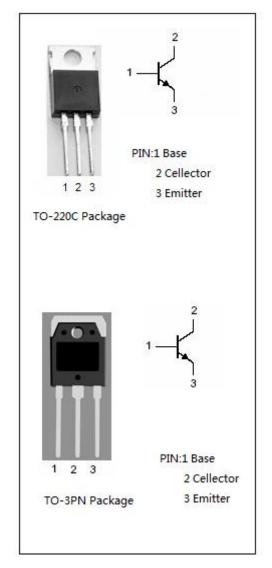
- · Energy-saving ligh
- High frequency switching power supply
- High frequency power transform

## ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25℃)

SYMBOL	PARAMETER	VALUE	UNIT		
V <sub>CEV</sub>	Collector-Emitter Voltage	600	V		
V <sub>CEO</sub>	Collector-Emitter Voltage	350	V		
V <sub>EBO</sub>	Emitter-Base Voltage	9	V		
Ic	Collector Current-Continuous	15	Α		
I <sub>CM</sub>	Collector Current-peak	30	Α		
I <sub>B</sub>	Base Current		7	Α	
I <sub>BM</sub>	Base Current-Peak		14	Α	
Pc	Collector Power Dissipation	TO-220	110	w	
	T <sub>C</sub> =25℃	TO-3PN	130	VV	
Ti	Junction Temperature		150	°C	
T <sub>stg</sub>	Storage Temperature Range		-55~150	$^{\circ}$ C	

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		MAX	UNIT	
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	TO-220	1.14	°C/W	
		TO-3PN	0.96	C/W	





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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub> =25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 10mA; I <sub>B</sub> = 0	350			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 8A ;I <sub>B</sub> = 1.6A			1.5	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 8A ;I <sub>B</sub> = 1.6A			1.6	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 600V; I <sub>E</sub> =0			0.1	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> =9V; I <sub>C</sub> = 0			0.01	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 5A; V <sub>CE</sub> = 5V	8		40	
h <sub>FE-2</sub>	DC Current Gain	Ic= 8A; VcE= 5V	8			

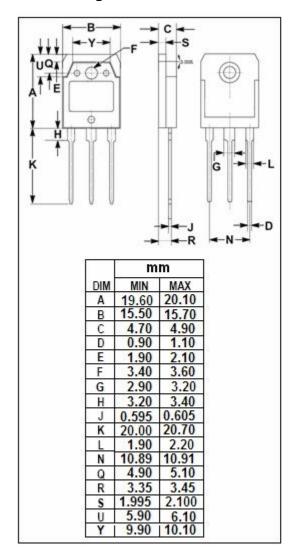


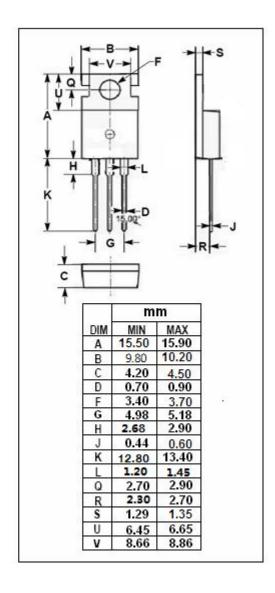


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## **Outline Drawing**





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